



Thunder High Power Products

FRED Ultrafast Soft Recovery Diode

FEATURES:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity

Benefits:

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced part count

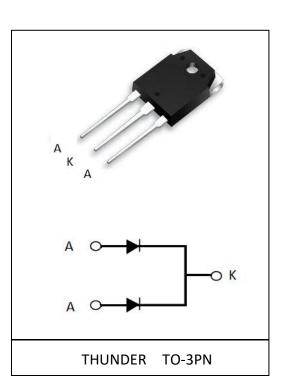
Product Summary		
VR	400 V	
lf(AV)	2*40A	
trr	25ns	

Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		400	V
Continuous forward current	lf(AV)	Tc =110°C	2*40	А
Single pulse forward current	IFSM	Tc =25°C	2*400	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	2*80	А
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C







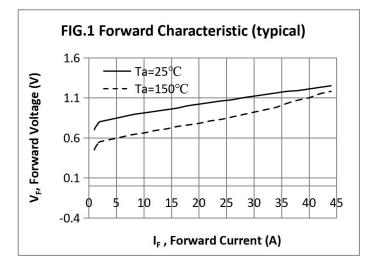
Electrical characteristics (Ta=25°C unless otherwise specified)

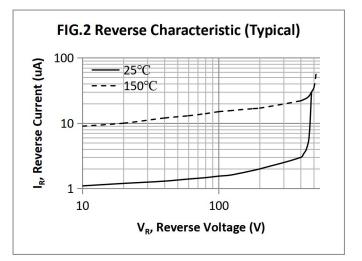
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage Blocking voltage	Vbr, Vr	Ir=100µA	400			
Forward voltage (Per Diode)	VF	IF=40A, Tj =25°C		1.20	1.40	V
		IF=40 A, Tj =125°C		1.10	1.30	
Reverse leakage current(Per Diode)	IR -	Vr= Vrrm			3	
		Tj=150°C, Vr=400V			40	μA
Reverse recovery time(Per Diode)	trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		35	55	20
		I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		25	35	ns

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{\theta JC}$	0.75	°C/W

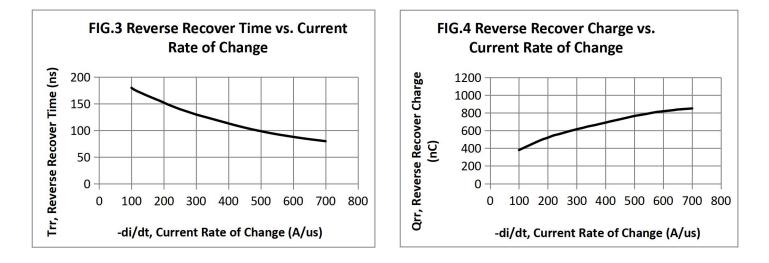
Electrical performance (typical single die)

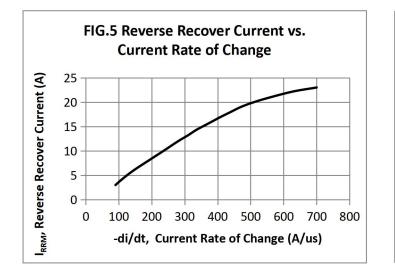


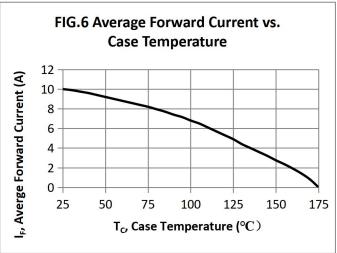


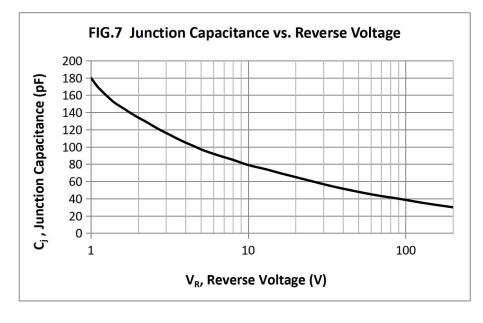


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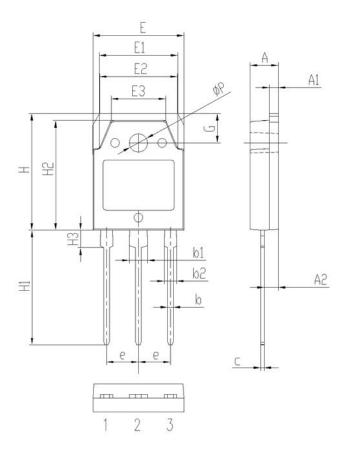








Package Information



Symbol	Dimensions(millimeters)		
Symbol	Min.	Max.	
A	4.60	5.00	
A1	1.30	1.70	
A2	2.20	2.60	
b	0.80	1.20	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
E	15.3	15.7	
E1	13.2	13.6	
E2	13.1	13.5	
E3	9.10	9.50	
Н	19.7	20.1	
H1	19.1	20.1	
H2	18.3	18.7	
H3	2.80	3.20	
G	4.80	5.20	
ΦР	3.00	3.40	

Notice

Thunder Microelectronics Incorporated Limited reserves the right to make changes without further notice to any products or specifications herein. When use the product, be sure to obtain the latest specification.

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PACKAGE

Thunder Microelectronics Incorporated Limited does not assume any liability arising out of the application or any product described herein. When using Thunder Microelectronics Incorporated Limited products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury ,fire or other problem if any of the products become faulty.

-Headquarters

WuXi Thunder Microelectronics Incorporated Limited Building E1-9F, No.200 LingHu Road, XinWu district,WuXi,China 214135 Tel:+86-510-85160109 Fax:+86-510-85160109